[10]

Claims

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An information storage medium of reproducing information, which is recorded [1] as marks smaller than a resolution of an incidence beam, the information storage medium comprising: a substrate; and a super resolution layer directly arranged on the substrate without any layer therebetween to reproduce the marks by generating a thermal reaction at a portion where the incidence beam is focused. [2] The information storage medium of claim 1, wherein the marks are formed on the substrate in a pit type. [3] The information storage medium of any one of claims 1 and 2, wherein the super resolution layer is formed of any one material selected from metal oxides formed of PtO, AuO, PdO, and AgO, or a polymer compound. [4] The information storage medium of any one of claims 1 and 2, further including at least one thermal absorption layer of absorbing the heat of the incidence beam. [5] The information storage medium of claim 4, wherein the thermal absorption layer is formed of any one of a Ge-Sb-Te-based alloy and an Ag-In-Sb-Te-based alloy. The information storage medium of claim 4, wherein a dielectric layer is [6] arranged between the super resolution layer and each of at least one thermal absorption layer. [7] An information storage medium of reproducing information, which is recorded as marks smaller than a resolution of an incidence beam, the information storage medium comprising: a substrate; and a thermal absorption layer directly arranged on the substrate without any layer therebetween to reproduce the marks by generating a thermal absorption at a portion where a reproducing beam is focused. [8] The information storage medium of claim 7 is a read only information storage medium. [9] The information storage medium of any one of claims 7 and 8, further including a super resolution layer formed on the thermal absorption layer and thermally r eacting with the reproducing beam.

The information storage medium of claim 9, wherein the super resolution layer is

formed of any one material selected from metal oxides formed of PtO, AuO, PdO, and AgO, or a polymer compound. [11] The information storage medium of claim 9, further including another thermal absorption layer on the super resolution layer. [12] The information storage medium of claim 9, wherein the thermal absorption layer is formed of any one of a Ge-Sb-Te-based alloy and an Ag-In-Sb-Te-based alloy. [13] The information storage medium of claim 9, wherein a dielectric layer is arranged between the thermal absorption layer and the super resolution layer. [14] A method of preventing a reproduing characteristic from being deteriorated when reproducing information, which is recorded as marks, from an information storage medium including a substrate on which the marks smaller than a resolution are recorded and a thermal absorption layer and/or a super resolution layer possibly reproduing the marks, the method comprising: radiating a reproducing beam higher than a predetermined temperature to the substrate to generate a thermal reaction on the thermal absorption layer and/or the super resolution layer; and exhausting a heat from the reproducing beam from the substrate by omitting a layer of disturbing the flow of the heat from the reproduing beam between the substrate and the thermal absorption layer or the substrate and the super resolution layer. [15] The method of claim 14, wherein the thermal absorption layer is formed of any one of a Ge-Sb-Te-based alloy and an Ag-In-Sb-Te-based alloy. [16] The method of any one of claims 14 and 15, wherein the super resolution layer is

formed of any one material selected from metal oxides formed of PtO, AuO,

PdO, and AgO, or a polymer compound.